

SUPER-FAST RECOVERY RECTIFIERS

Features	◆ Ultrafast 35 Nanosecond Recovery Time ◆ 150° C Operating Junction Temperature ◆ Popular T0-247 Package ◆ High Temperature Glass Passivated Junction ◆ Low Forward Voltage ◆ Low Leakage Current ◆ Reverse Voltage to 600 Volts ◆ Pb-Free Packages are Available
----------	--

Typical Reference Data

VRRM= 200V
IF(AV)= 20A

VRRM= 400V
IF(AV)= 20A

VRRM= 600V
IF(AV)= 20A

Mechanical Characteristics	● Case: Epoxy, Molded ● Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable ● Lead Temperature for Soldering Purposes: 260° C Max. for 10 Seconds ● Shipped 50 units per plastic tube
----------------------------	--

MAXIMUM RATINGS

Rating	Symbol	MUR2020	MUR2040	MUR2060	Unit
Peak Repetitive Reverse Voltage	VRRM	200	400	600	V
Working Peak Reverse Voltage	VRWM				
DC Blocking Voltage	VR				
Average Rectified Forward Current	IF(AV)	10			A
Total Device, (Rated VR), TC = 150°C		20			
Peak Repetitive Forward Current	IFM	21			A
(Rated VR, Square Wave, 20 kHz), TC = 150°C					
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave , single phase, 60 Hz)	IFSM	150			A
Operating Junction Temperature and Storage Temperature	TJ, Tstg	- 40 to +150			°C

THERMAL CHARACTERISTICS (Per Diode Leg)

Maximum Thermal Resistance, Junction to Case	R θ JC	1.1	°C/W
--	---------------	-----	------

ELECTRICAL CHARACTERISTICS (Per Diode Leg)

Maximum Instantaneous Forward Voltage (1) (IF = 15.0 Amps, TC = 25° C)	VF	1.1	1.4	1.7	V
Maximum Instantaneous Reverse Current (1) (Rated dc Voltage, TJ = 150° C)	IR	500	500	500	μ A
(Rated dc Voltage, TJ = 25° C)		10	10	10	
Maximum Reverse Recovery Time (IF = 0.5 A, IR = 1.0 A, IREC = 0.25 A)	Trr	35			ns

(1) Pulse Test: Pulse Width = 300 μ s, Duty Cycle $\leq$ 2.0%.

SUPER-FAST RECOVERY RECTIFIERS

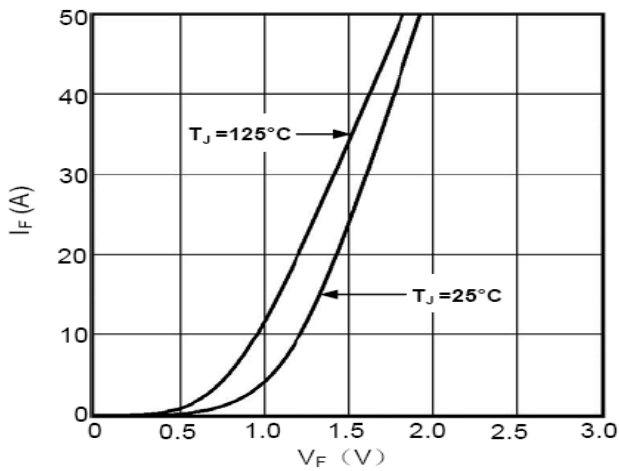


Fig1. Forward Voltage Drop vs Forward Current

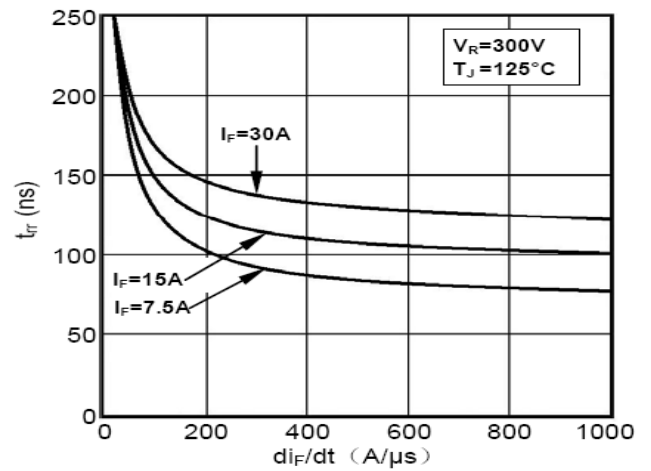


Fig2. Reverse Recovery Time vs di_F/dt

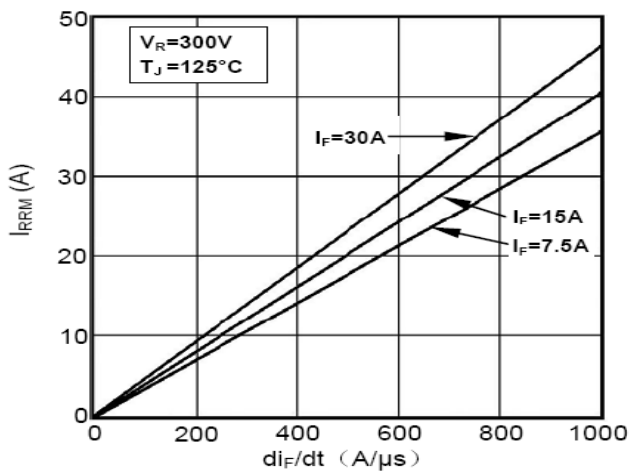


Fig3. Reverse Recovery Current vs di_F/dt

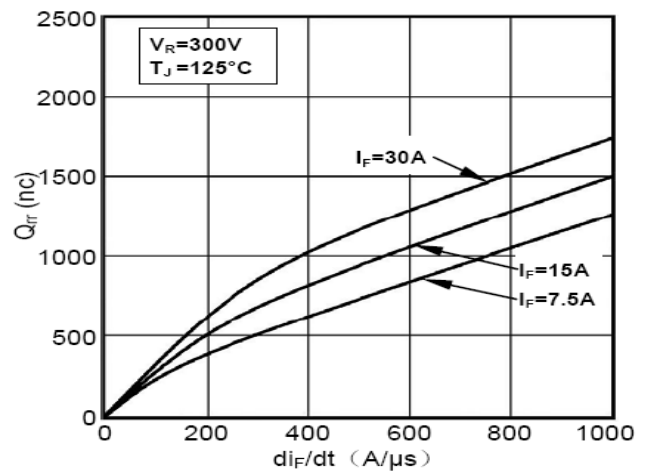


Fig4. Reverse Recovery Charge vs di_F/dt

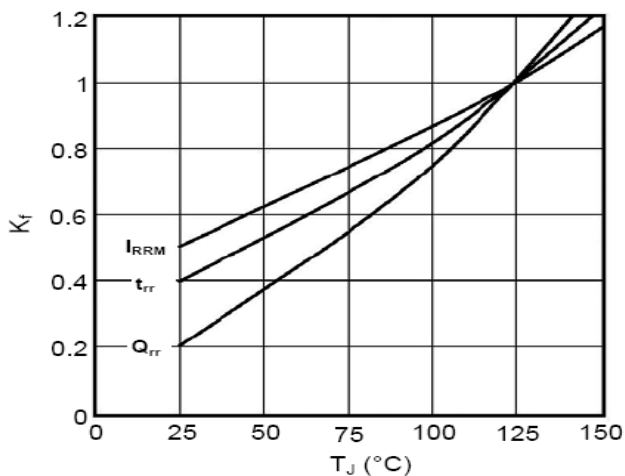


Fig5. Dynamic Parameters vs Junction Temperature

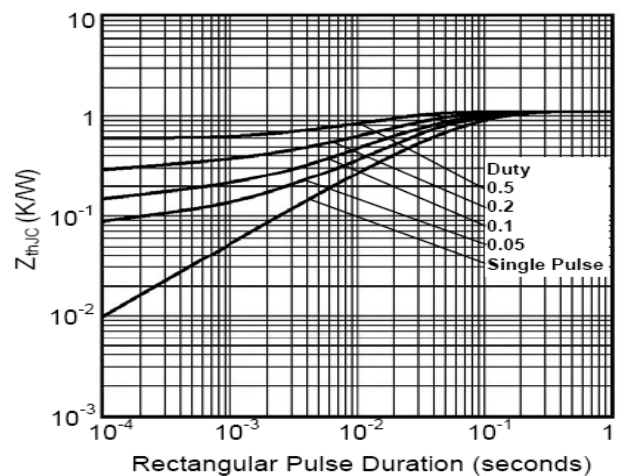
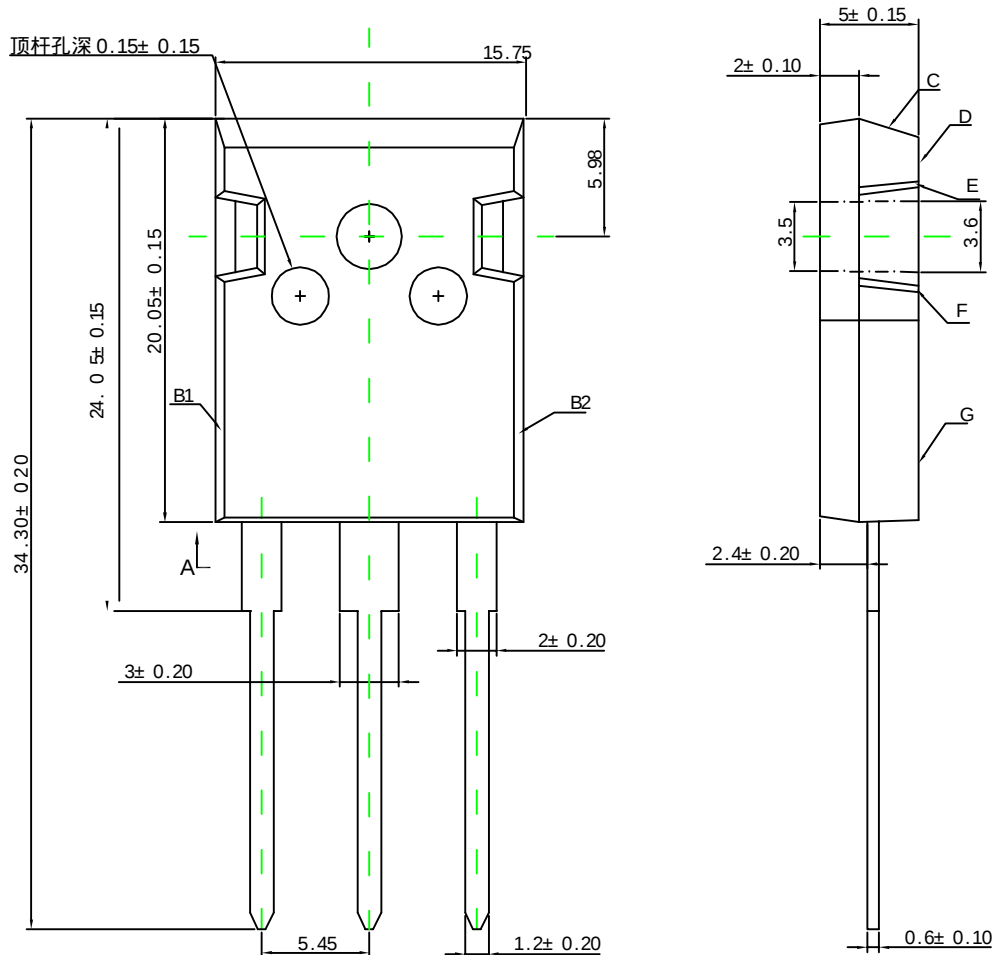


Fig6. Transient Thermal Impedance

SUPER-FAST RECOVERY RECTIFIERS

T0-247 /3PAB

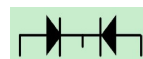


注意事项:

- XXXX代表日期码，第一码表示公元年的最后一码，第二码表示生产时当月码 (A, B, C... 为一月，二月，三月...)，第三，四码表示大量生产时批次码。
例如:2009年第一月生产的，D/C为9AXX。
- 包装及出货:ROHS, 30PCS/管, 0.6K/BOX, 1.8K(1.8K BOXEX)/CARTON, BOXEX及 CARTON。

ASEMI

MUR2060PT



XXXX

修订内容